

## Monolithic, Quad SPST, CMOS Analog Switches

The DG441 and DG442 monolithic CMOS analog switches are drop-in replacements for the popular DG201A and DG202 series devices. They include four independent single pole single throw (SPST) analog switches, TTL and CMOS compatible digital inputs, and a voltage reference for logic thresholds.

These switches feature lower analog ON resistance (<85Ω) and faster switch time ( $t_{ON} < 250\text{ns}$ ) compared to the DG201A and DG202. Charge injection has been reduced, simplifying sample and hold applications.

The improvements in the DG441 series are made possible by using a high voltage silicon-gate process. An epitaxial layer prevents the latch-up associated with older CMOS technologies. The 44V maximum voltage range permits controlling 40V<sub>P-P</sub> signals. Power supplies may be single-ended from +5V to +34V, or split from ±5V to ±20V.

The four switches are bilateral, equally matched for AC or bidirectional signals. The ON resistance variation with analog signals is quite low over a ±5V analog input range. The switches in the DG441 and DG442 are identical, differing only in the polarity of the selection logic.

## Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. DWG. #
DG441DJ	-40 to 85	16 Ld PDIP	E16.3
DG441DJZ (See Note)	-40 to 85	16 Ld PDIP (Pb-free)	E16.3
DG441DY	-40 to 85	16 Ld SOIC	M16.15
DG441DY-T	16 Ld SOIC Tape and Reel		M16.15
DG441DYZ (See Note)	-40 to 85	16 Ld SOIC (Pb-free)	M16.15
DG441DYZ-T (See Note)	16 Ld SOIC Tape and Reel (Pb-free)		M16.15
DG442DJ	-40 to 85	16 Ld PDIP	E16.3
DG442DJZ (See Note)	-40 to 85	16 Ld PDIP (Pb-free)	E16.3
DG442DY	-40 to 85	16 Ld SOIC	M16.15
DG442DY-T	16 Ld SOIC Tape and Reel		M16.15
DG442DYZ-T (See Note)	16 Ld SOIC Tape and Reel (Pb-free)		M16.15

NOTE: Intersil Pb-free products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which is compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J Std-020B.

## Features

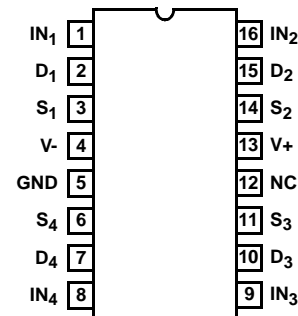
- ON Resistance (Max) . . . . . 85Ω
- Low Power Consumption ( $P_D$ ) . . . . . <1.6mW
- Fast Switching Action
  - $t_{ON}$  (Max) . . . . . 250ns
  - $t_{OFF}$  (Max, DG441) . . . . . 120ns
- Low Charge Injection
- Upgrade from DG201A/DG202
- TTL, CMOS Compatible
- Single or Split Supply Operation
- Pb-free Available

## Applications

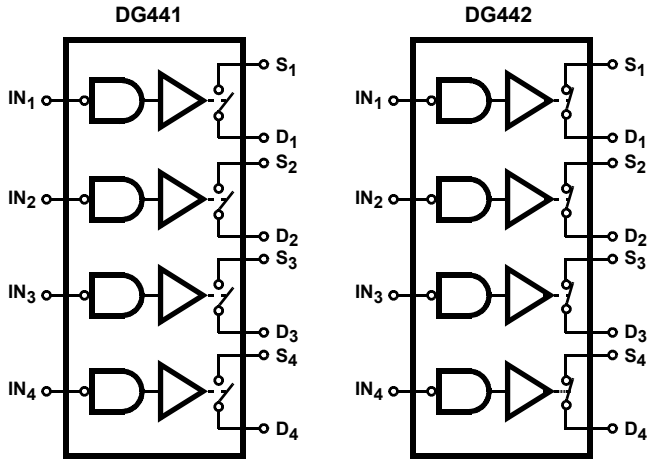
- Audio Switching
- Battery Operated Systems
- Data Acquisition
- Hi-Rel Systems
- Sample and Hold Circuits
- Communication Systems
- Automatic Test Equipment

## Pinout

**DG441, DG442  
(PDIP, SOIC)  
TOP VIEW**



**Functional Diagrams**

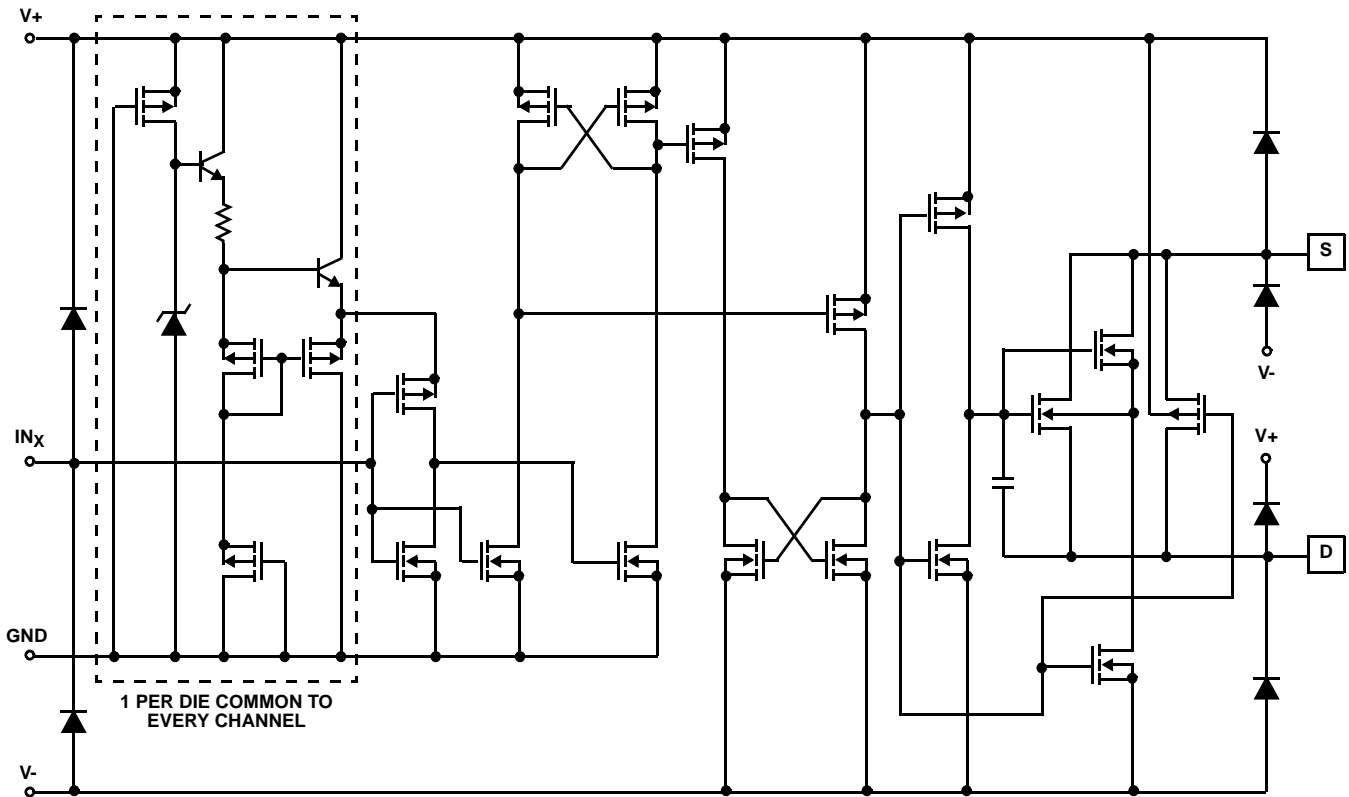


SWITCHES SHOWN FOR LOGIC "1" INPUT

TRUTH TABLE

LOGIC	V <sub>IN</sub>	DG441	DG442
0	≤0.8V	ON	OFF
1	≥2.4V	OFF	ON

**Schematic Diagram** (One Channel)



**Pin Descriptions**

PIN	SYMBOL	DESCRIPTION
1	$IN_1$	Logic Control for Switch 1
2	$D_1$	Drain (Output) Terminal for Switch 1
3	$S_1$	Source (Input) Terminal for Switch 1
4	$V-$	Negative Power Supply Terminal
5	$GND$	Ground Terminal (Logic Common)
6	$S_4$	Source (Input) Terminal for Switch 4
7	$D_4$	Drain (Output) Terminal for Switch 4
8	$IN_4$	Logic Control for Switch 4
9	$IN_3$	Logic Control for Switch 3
10	$D_3$	Drain (Output) Terminal for Switch 3
11	$S_3$	Source (Input) Terminal for Switch 3
12	NC	No Internal Connection
13	$V+$	Positive Power Supply Terminal (Substrate)
14	$S_2$	Source (Input) Terminal for Switch 2
15	$D_2$	Drain (Output) Terminal for Switch 2
16	$IN_2$	Logic Control for Switch 2

**Absolute Maximum Ratings**

V+ to V-	44.0V
GND to V-	25V
Digital Inputs, V <sub>S</sub> , V <sub>D</sub> (Note 1)	(V-) -2V to (V+) + 2V or 30mA, Whichever Occurs First
Continuous Current (Any Terminal)	30mA
Peak Current, S or D (Pulsed 1ms, 10% Duty Cycle Max)	100mA

**Thermal Information**

Thermal Resistance (Typical, Note 2)	$\theta_{JA}$ (°C/W)
PDIP Package	90
SOIC Package	115
Maximum Junction Temperature (Plastic Packages)	150°C
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C (SOIC - Lead Tips Only)

**Operating Conditions**

Temperature Range	-40°C to 85°C
Voltage Range	±20V (Max)
Input Low Voltage	0.8V (Max)
Input High Voltage	2.4V (Min)
Input Rise and Fall Time	≤20ns

*CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

**NOTES:**

1. Signals on S<sub>X</sub>, D<sub>X</sub> or IN<sub>X</sub> exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
2.  $\theta_{JA}$  is measured with the component mounted on an evaluation PC board in free air.

**Electrical Specifications** (Dual Supply) Test Conditions: V+ = +15V, V- = -15V, V<sub>IN</sub> = 2.4V, 0.8V, V<sub>ANALOG</sub> = V<sub>S</sub>, V<sub>D</sub>, Unless Otherwise Specified

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN	(NOTE 3) TYP	MAX	UNITS
<b>DYNAMIC CHARACTERISTICS</b>						
Turn-ON Time, t <sub>ON</sub>	R <sub>L</sub> = 1k $\Omega$ , C <sub>L</sub> = 35pF, V <sub>S</sub> = ±10V, (Figure 1)	25	-	150	250	ns
Turn-OFF Time, t <sub>OFF</sub>		25	-	90	120	ns
				DG441	110	210
Charge Injection, Q (Figure 2)	C <sub>L</sub> = 1nF, V <sub>G</sub> = 0V, R <sub>G</sub> = 0 $\Omega$	25	-	-1	-	pC
OFF Isolation (Figure 4)	R <sub>L</sub> = 50 $\Omega$ , C <sub>L</sub> = 5pF, f = 1MHz	25	-	60	-	dB
Crosstalk (Channel-to-Channel) (Figure 3)		25	-	-100	-	dB
Source OFF Capacitance, C <sub>S(OFF)</sub>	f = 1MHz, V <sub>ANALOG</sub> = 0 (Figure 5)	25	-	4	-	pF
Drain OFF Capacitance, C <sub>D(OFF)</sub>		25	-	4	-	pF
Channel ON Capacitance, C <sub>D(ON)</sub> + C <sub>S(ON)</sub>		25	-	16	-	pF
<b>DIGITAL INPUT CHARACTERISTICS</b>						
Input Current V <sub>IN</sub> Low, I <sub>IL</sub>	V <sub>IN</sub> Under Test = 0.8V, All Others = 2.4V	Full	-0.5	-0.00001	0.5	$\mu$ A
Input Current V <sub>IN</sub> High, I <sub>IH</sub>	V <sub>IN</sub> Under Test = 2.4V, All Others = 0.8V	Full	-0.5	0.00001	0.5	$\mu$ A
<b>ANALOG SWITCH CHARACTERISTICS</b>						
Analog Signal Range, V <sub>ANALOG</sub>		Full	-15	-	15	V
Drain-Source ON Resistance, r <sub>DS(ON)</sub>	I <sub>S</sub> = $\mp$ 10mA, V <sub>D</sub> = ±8.5V, V+ = 13.5V, V- = -13.5V	25	-	50	85	$\Omega$
		85	-	-	100	$\Omega$
Source OFF Leakage Current, I <sub>S(OFF)</sub>	V+ = 16.5V, V- = -16.5V, V <sub>D</sub> = ±15.5V, V <sub>S</sub> = $\mp$ 15.5V	25	-0.5	0.01	0.5	nA
		85	-5	-	5	nA
Drain OFF Leakage Current, I <sub>D(OFF)</sub>		25	-0.5	0.01	0.5	nA
		85	-5	-	5	nA
Channel ON Leakage Current, I <sub>D(ON)</sub> + I <sub>S(ON)</sub>	V+ = 16.5V, V- = -16.5V, V <sub>S</sub> = V <sub>D</sub> = ±15.5V	25	-0.5	0.08	0.5	nA
		85	-10	-	10	nA
<b>POWER SUPPLY CHARACTERISTICS</b>						
Positive Supply Current, I+	V+ = 16.5V, V- = -16.5V, V <sub>IN</sub> = 0V or 5V	Full	-	15	100	$\mu$ A
		25	-1	-0.0001	-	$\mu$ A
Negative Supply Current, I-		Full	-5	-	-	$\mu$ A
		Full	-100	-15	-	$\mu$ A

**Electrical Specifications** (Single Supply) Test Conditions:  $V_+ = 12V$ ,  $V_- = 0V$ ,  $V_{IN} = 2.4V, 0.8V$ , Unless Otherwise Specified

PARAMETER	TEST CONDITIONS	TEMP (°C)	MIN	(NOTE 3) TYP	MAX	UNITS
<b>DYNAMIC CHARACTERISTICS</b>						
Turn-ON Time, $t_{ON}$	$R_L = 1k\Omega$ , $C_L = 35pF$ , $V_S = 8V$ , (Figure 1)	25	-	300	450	ns
Turn-OFF Time, $t_{OFF}$		25	-	60	200	ns
Charge Injection, Q (Figure 2)	$C_L = 1nF$ , $V_G = 6V$ , $R_G = 0\Omega$	25	-	2	-	pC
<b>ANALOG SWITCH CHARACTERISTICS</b>						
Analog Signal Range, $V_{ANALOG}$		Full	0	-	12	V
Drain-Source ON Resistance, $r_{DS(ON)}$	$I_S = 10mA$ , $V_D = 3V$ , $8V$ $V_+ = 10.8V$	25	-	100	160	$\Omega$
		Full	-	-	200	$\Omega$
<b>POWER SUPPLY CHARACTERISTICS</b>						
Positive Supply Current, $I_+$	$V_+ = 13.2V$ , $V_- = 0V$ , $V_{IN} = 0V$ or $5V$	Full	-	15	100	$\mu A$
Negative Supply Current, $I_-$		25	-1	-0.0001	-	$\mu A$
		Full	-100	-0.0001	-	$\mu A$
Ground Current, $I_{GND}$		Full	-100	-15	-	$\mu A$

NOTES:

3. Typical values are for DESIGN AID ONLY, not guaranteed nor production tested.

**Test Circuits and Waveforms**

$V_O$  is the steady state output with the switch on. Feedthrough via switch capacitance may result in spikes at the leading and trailing edge of the output waveform.

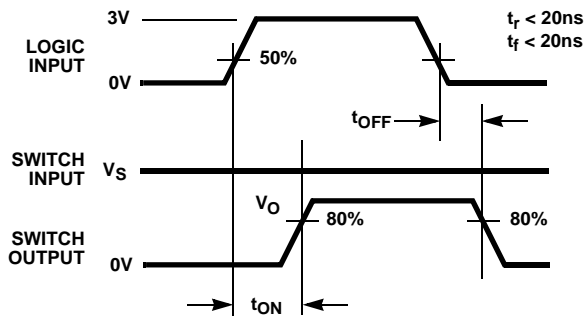
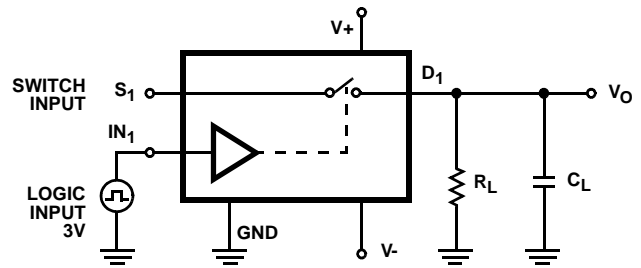


FIGURE 1A. MEASUREMENT POINTS



Repeat test for Channels 2, 3 and 4.

For load conditions, see Specifications.  $C_L$  includes fixture and stray capacitance.

$$V_O = V_S \frac{R_L}{R_L + r_{DS(ON)}}$$

FIGURE 1B. TEST CIRCUIT

FIGURE 1. SWITCHING TIMES

NOTE: Logic input waveform is inverted for switches that have the opposite logic sense.

Test Circuits and Waveforms (Continued)

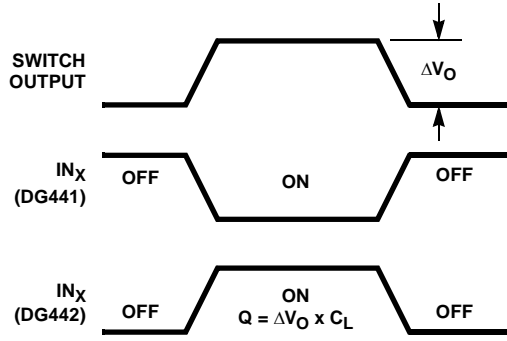


FIGURE 2A. MEASUREMENT POINTS

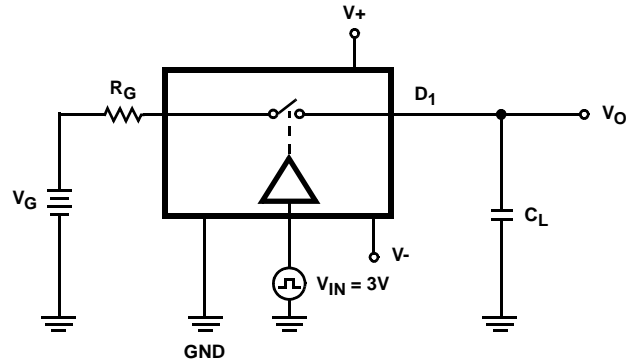


FIGURE 2B. TEST CIRCUIT

FIGURE 2. CHARGE INJECTION

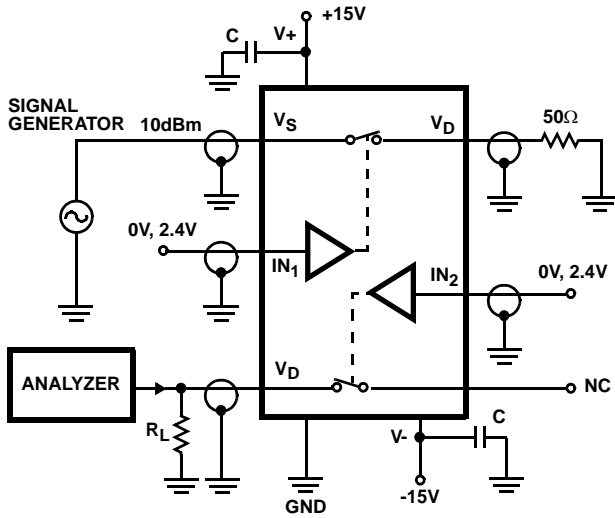


FIGURE 3. CROSSTALK TEST CIRCUIT

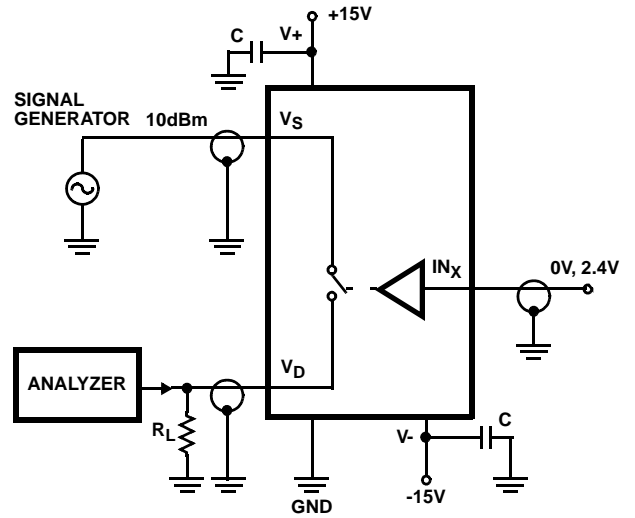


FIGURE 4. OFF ISOLATION TEST CIRCUIT

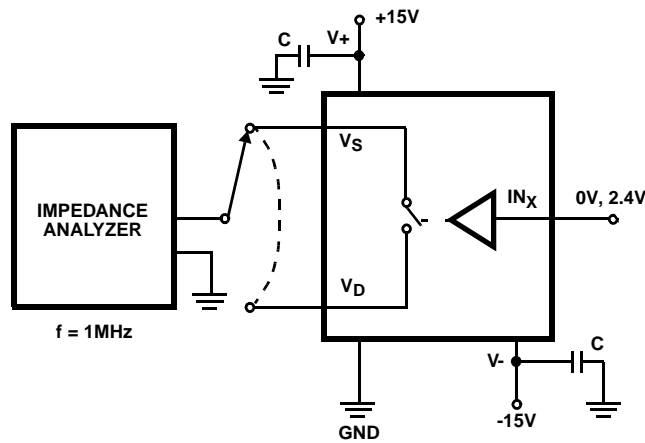
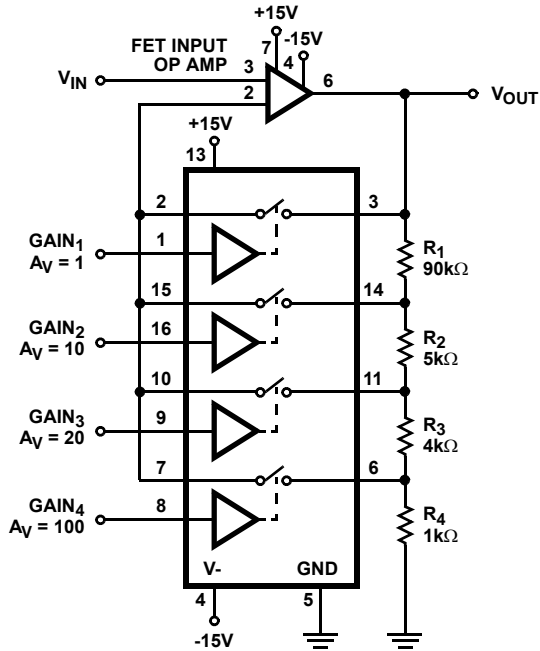


FIGURE 5. SOURCE/DRAIN CAPACITANCES TEST CIRCUIT

### Application Information

GAIN ERROR IS DETERMINED ONLY BY THE RESISTOR TOLERANCE. OP AMP OFFSET AND CMRR WILL LIMIT ACCURACY OF CIRCUIT.



$$\frac{V_{OUT}}{V_{IN}} = \frac{R_1 + R_2 + R_3 + R_4}{R_4} = 100 \text{ with SW}_4 \text{ closed}$$

FIGURE 6. PRECISION WEIGHTED RESISTOR PROGRAMMABLE GAIN AMPLIFIER

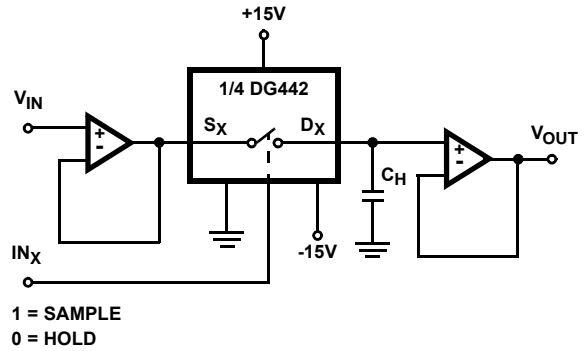


FIGURE 7. OPEN LOOP SAMPLE AND HOLD

### Typical Performance Curves

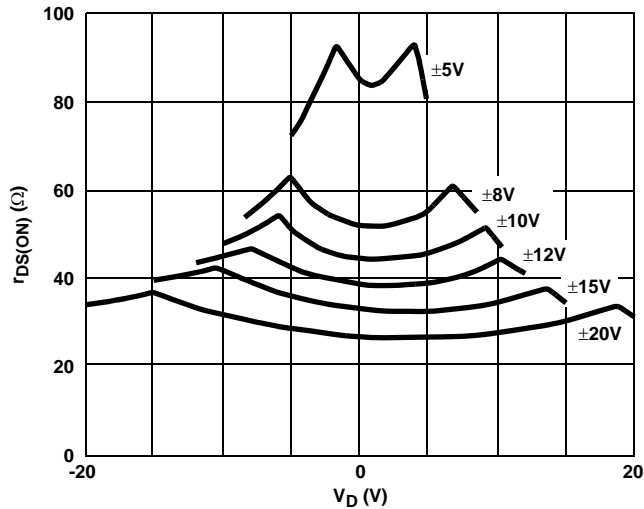


FIGURE 8.  $r_{DS(ON)}$  vs  $V_D$  AND POWER SUPPLY VOLTAGE

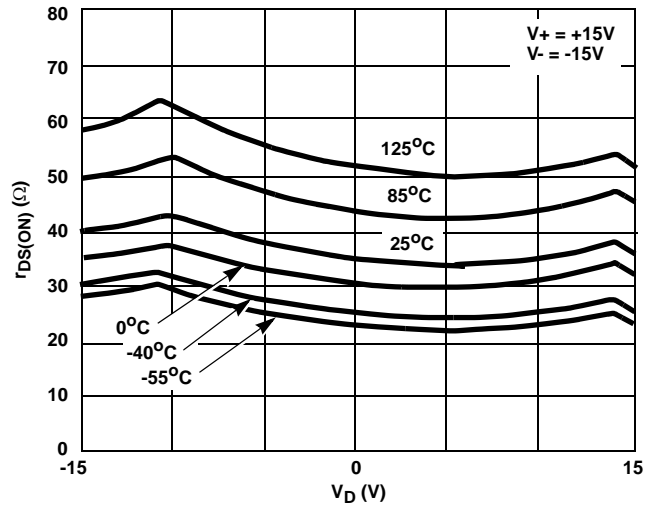


FIGURE 9.  $r_{DS(ON)}$  vs  $V_D$  AND TEMPERATURE

Typical Performance Curves (Continued)

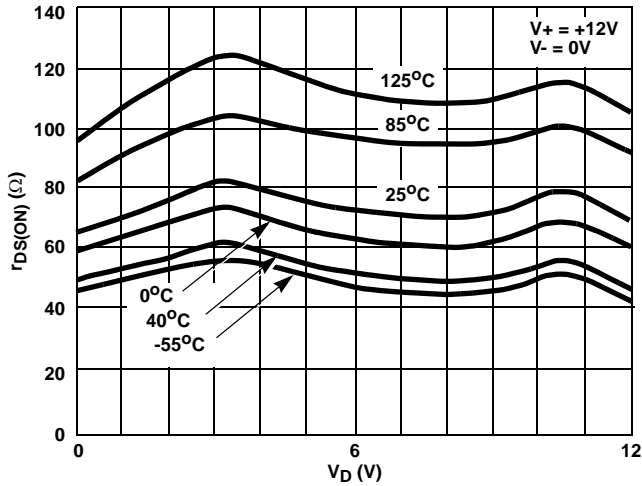


FIGURE 10.  $r_{DS(ON)}$  vs  $V_D$  AND TEMPERATURE (SINGLE 12V SUPPLY)

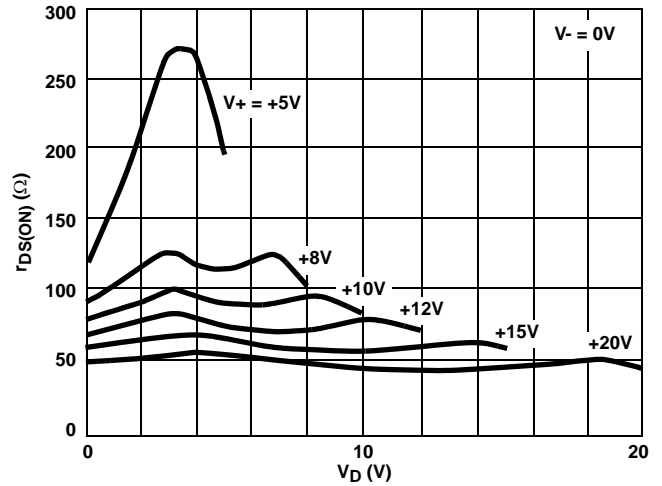


FIGURE 11.  $r_{DS(ON)}$  vs  $V_D$  AND SINGLE SUPPLY VOLTAGE

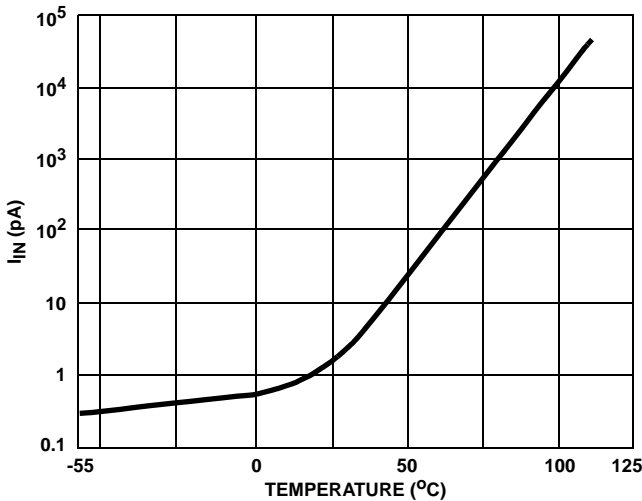


FIGURE 12. INPUT CURRENT vs TEMPERATURE

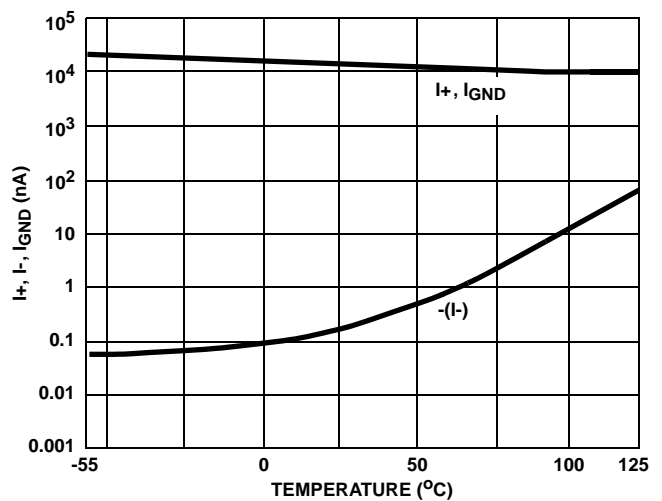


FIGURE 13. SUPPLY CURRENT vs TEMPERATURE

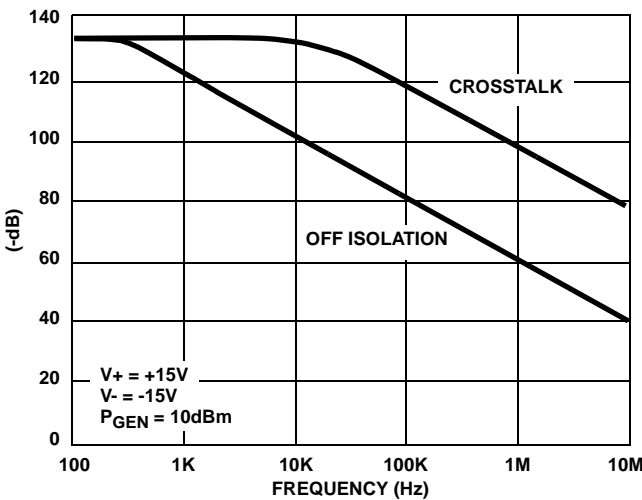


FIGURE 14. CROSSTALK AND OFF ISOLATION vs FREQUENCY

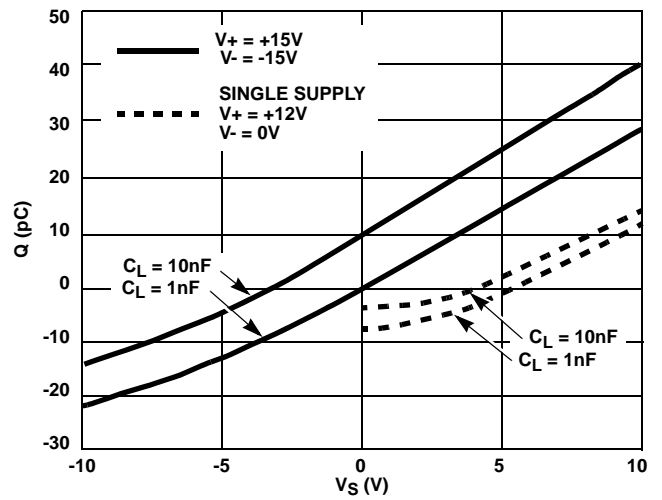


FIGURE 15. CHARGE INJECTION vs SOURCE VOLTAGE



Typical Performance Curves (Continued)

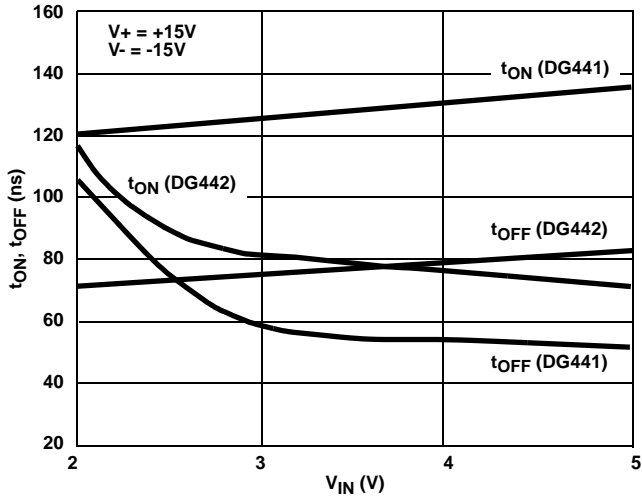


FIGURE 16. SWITCHING TIMES vs INPUT VOLTAGE

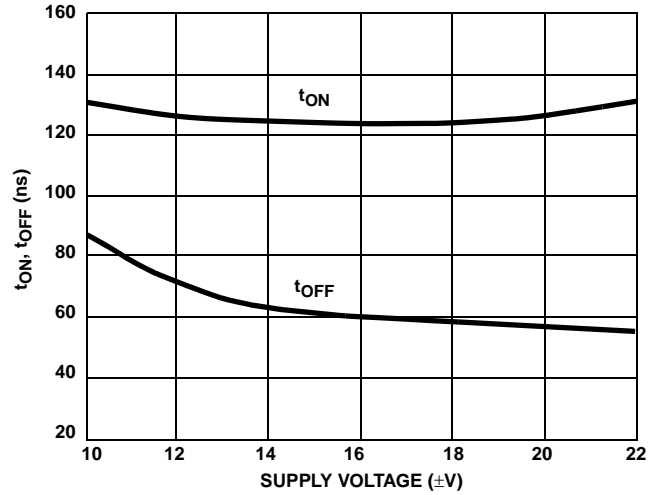


FIGURE 17. SWITCHING TIME vs POWER SUPPLY VOLTAGE (DG441)

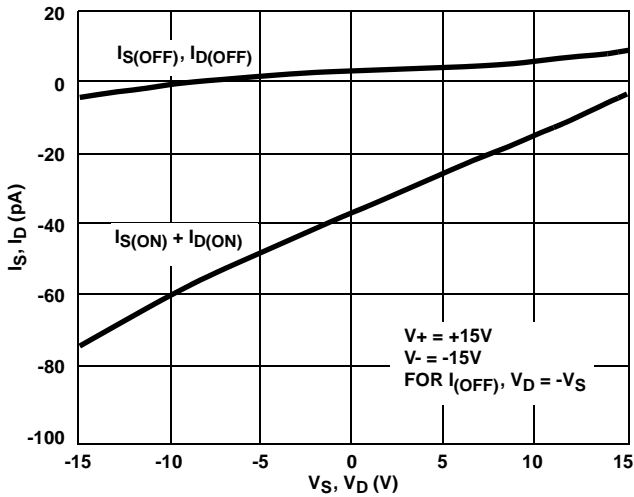


FIGURE 18. LEAKAGE CURRENT vs ANALOG VOLTAGE

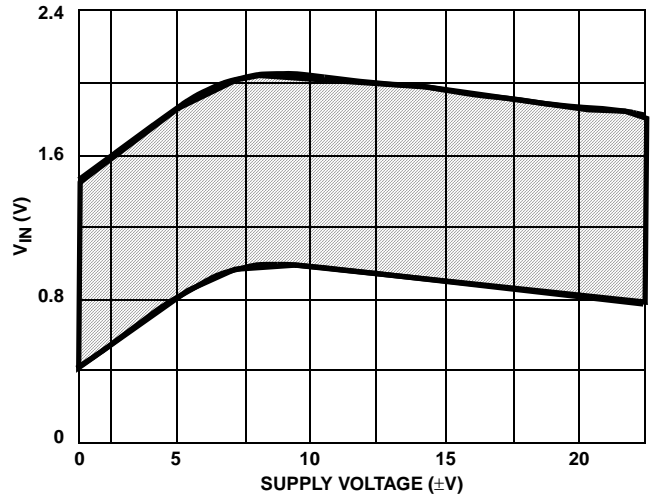


FIGURE 19. SWITCHING THRESHOLD vs SUPPLY VOLTAGE

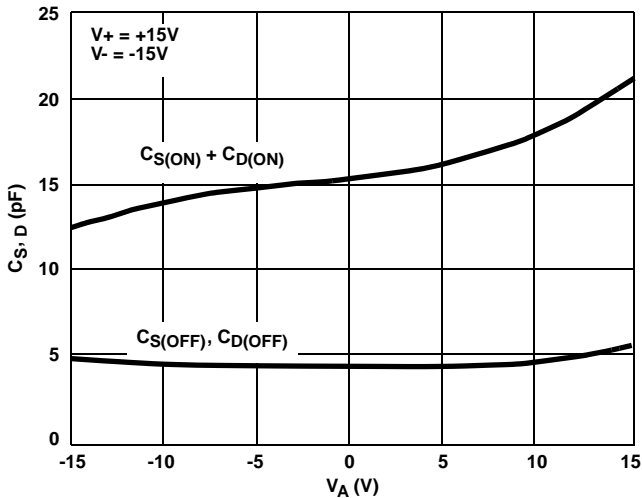


FIGURE 20. SOURCE/DRAIN CAPACITANCE vs ANALOG VOLTAGE

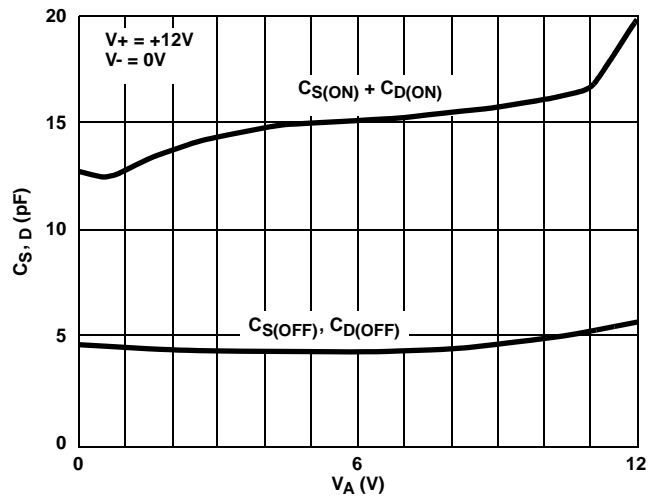


FIGURE 21. SOURCE/DRAIN CAPACITANCE vs ANALOG VOLTAGE (SINGLE 12V SUPPLY)

Typical Performance Curves (Continued)

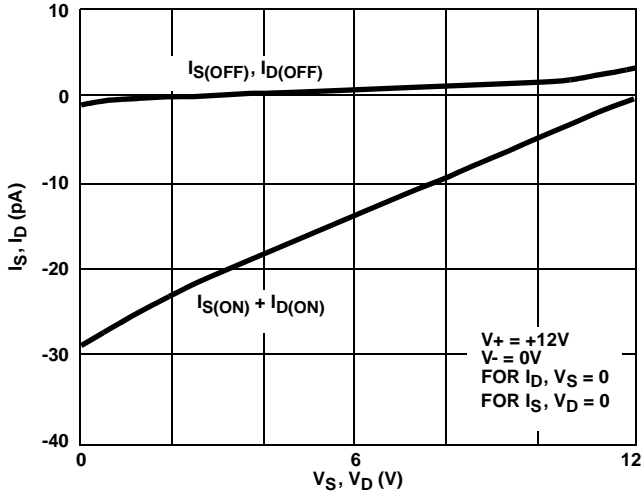


FIGURE 22. SOURCE/DRAIN LEAKAGE CURRENTS (SINGLE 12V SUPPLY)

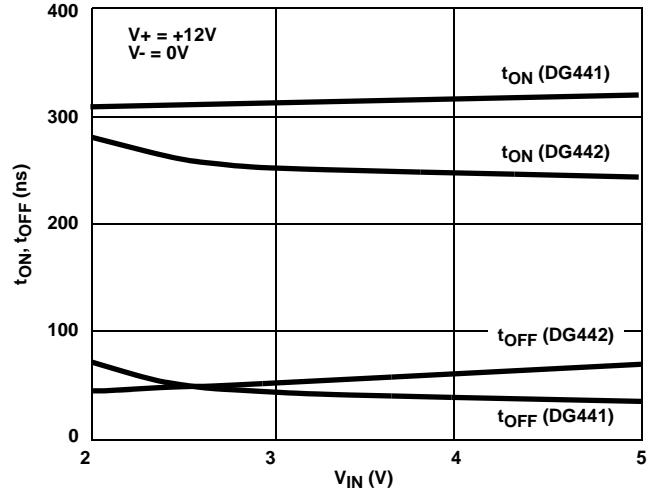


FIGURE 23. SWITCHING TIME vs INPUT VOLTAGE (SINGLE 12V SUPPLY)

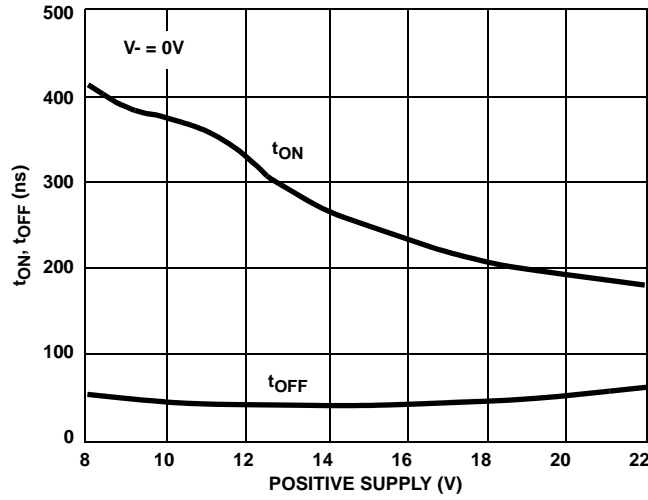


FIGURE 24. SWITCHING TIME vs SINGLE SUPPLY VOLTAGE (DG441)

**Die Characteristics**

**DIE DIMENSIONS:**

2160 $\mu$ m x 1760 $\mu$ m x 485 $\mu$ m

**METALLIZATION:**

Type: SiAl

Thickness: 12k $\text{\AA}$   $\pm$  1k $\text{\AA}$

**PASSIVATION:**

Type: Nitride

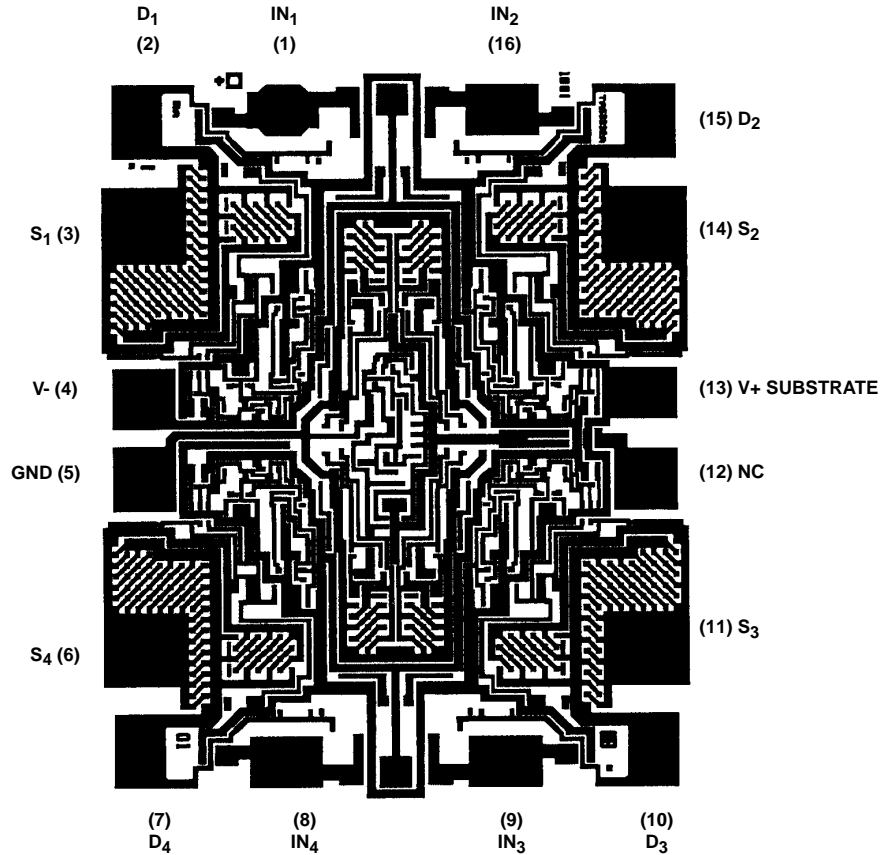
Thickness: 8k $\text{\AA}$   $\pm$  1k $\text{\AA}$

**WORST CASE CURRENT DENSITY:**

9.1 x 10<sup>4</sup> A/cm<sup>2</sup>

**Metallization Mask Layout**

DG441, DG442



All Intersil U.S. products are manufactured, assembled and tested utilizing ISO9000 quality systems.

Intersil Corporation's quality certifications can be viewed at [www.intersil.com/design/quality](http://www.intersil.com/design/quality)

*Intersil products are sold by description only. Intersil Corporation reserves the right to make changes in circuit design, software and/or specifications at any time without notice. Accordingly, the reader is cautioned to verify that data sheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.*

For information regarding Intersil Corporation and its products, see [www.intersil.com](http://www.intersil.com)